

SSCE5V031N1

1-Line Uni-directional low Capacitance TVS Diode

Description

The SSCE5V031N1 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The SSCE5V031N1 has an ultra-low capacitance with a typical value at 0.4pF, and complies with the IEC 61000-4-2 (ESD) with ±20kV air and ±15kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package.

Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, USB 3.0 super speed, VGA, DVI, HDMI, SDI and other high speed line applications.

Features

- \Rightarrow 64W peak pulse power (t_P = 8/20µs)
- ♦ DFN1006-2L Package
- ♦ Working voltage:5V
- ♦ Low Leakage Current
- ♦ Low capacitance
- ♦ Low clamping voltage
- ♦ Response Time is Typically<1ns</p>
- ♦ Complies with following standards:
 - -IEC61000-4-2(ESD) ±15kV(contact),
 - ±20kV(air)
 - IEC61000-4-4 (EFT) 40A (5/50ns)
 - -IEC61000-4-5(Lightning) 4A(8/20µs)

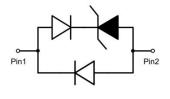
Mechanical Characteristics

- ♦ Case Material: "Green" Molding Compound.
- ♦ UL Flammability Classification Rating 94V-0
- ♦ Moisture Sensitivity: Level 3 per J-STD-020

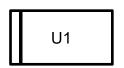
PIN configuration



DFN1006-2L (Bottom View)



Circuit Diagram



Marking (Top View)

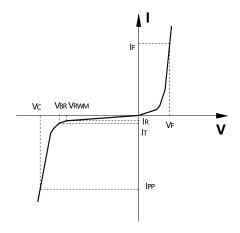
Applications

- ♦ DVI & HDMI Port Protection
- ♦ SATA and eSATA
- ♦ Serial and Parallel Ports
- ♦ Projection TV
- ♦ Notebooks, Desktops, Servers
- ♦ Digital cameras



• Electronic Parameter

| Symbol | Parameter | | |
|-----------------|--|--|--|
| V_{RWM} | Peak Reverse Working Voltage | | |
| I _R | Reverse Leakage Current @ V _{RWM} | | |
| V_{BR} | Breakdown Voltage @ I _T | | |
| I _T | Test Current | | |
| I _{PP} | Maximum Reverse Peak Pulse Current | | |
| Vc | Clamping Voltage @ IPP | | |
| P _{PP} | Peak Pulse Power | | |
| Сл | Junction Capacitance | | |



Absolute maximum rating (T_A=25^oC unless otherwise noted)

| Parameter | | Symbol | Value | Units |
|------------------------------|---------|------------------|----------|---------------|
| Peak Pulse Power (8/20µs) | | P_PP | 64 | W |
| Peak Pulse Current (8/20µs) | | I _{PP} | 4 | Α |
| ESD Rating per IEC61000-4-2: | Contact | W | ±15 | kV |
| | Air | V_{ESD} | ±20 | |
| Storage Temperature | | T _{STG} | -55/+150 | $^{\circ}$ |
| Operating Temperature | | TJ | -55/+125 | ${\mathbb C}$ |

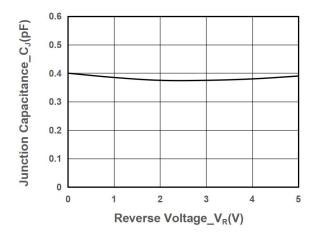
Electrical Characteristics (T_A=25^oC unless otherwise noted)

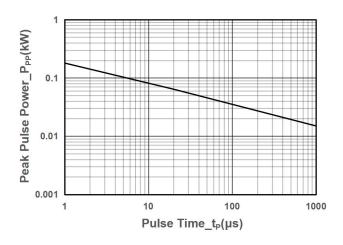
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|------------------------------|----------------|------------------------------------|------|------|------|-------|
| Peak Reverse Working Voltage | V_{RWM} | | | | 5 | V |
| Breakdown Voltage | V_{BR} | $I_T = 1mA$ | 6 | | | V |
| Reverse Leakage Current | I _R | $V_{RWM} = 5V$ | | 0.03 | 0.2 | μΑ |
| Forward Voltage | V _F | I _F = 15mA | | | 1.2 | V |
| Clamping Voltage | Vc | $I_{PP} = 1A$, $t_P = 8/20 \mu s$ | | | 10 | V |
| Clamping Voltage | Vc | $I_{PP} = 4A$, $t_P = 8/20 \mu s$ | | | 16 | V |
| Junction Capacitance | CJ | $V_R = 0V$, $f = 1MHz$ | | 0.4 | 0.8 | pF |

SSC-V1.3 <u>www.sscsemi.com</u> Analog Future

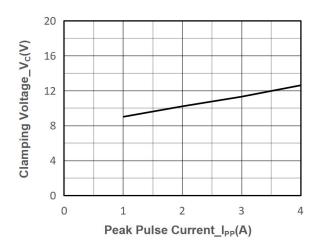


Typical Performance Characteristics (T_A=25℃ unless otherwise noted)

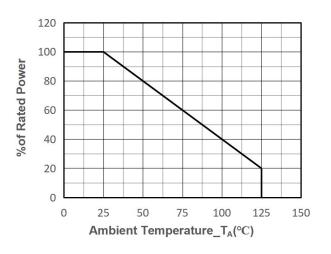




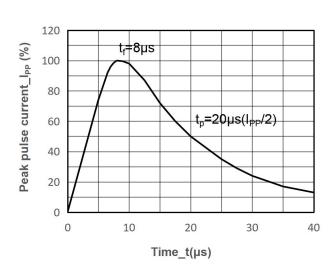
Junction Capacitance vs. Reverse Voltage



Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current



Power derating vs. Ambient temperature

8/20µs Pulse Waveform

SSC-V1.3 www.sscsemi.com **Analog Future**



Package Information

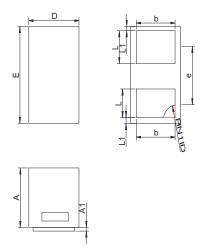
Ordering Information

| Device | Package | Qty per Reel | Reel Size | |
|-------------|------------|--------------|-----------|--|
| SSCE5V031N1 | DFN1006-2L | 10000 | 7 Inch | |

Mechanical Data

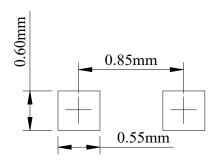
Case: DFN1006-2L

Case Material: Molded Plastic. UL Flammability



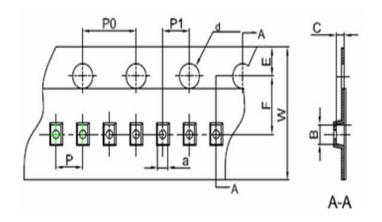
| DIM | Millimeters | | | |
|------------|-------------|------|--|--|
| DIIVI | Min | Max | | |
| Α | 0.45 | 0.55 | | |
| A 1 | 0.00 | 0.05 | | |
| D | 0.55 | 0.65 | | |
| E | 0.95 | 1.05 | | |
| b | 0.45 | 0.60 | | |
| е | 0.65TYP | | | |
| L | 0.2 | 0.3 | | |
| L1 | 0.05REF | | | |

Recommended Pad outline (Unit: mm)

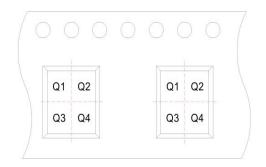




• Type and Reel Information-DFN1006-2L

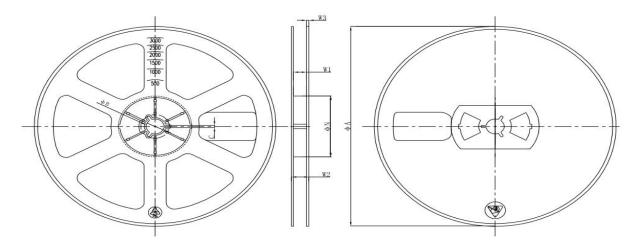


| DIM | Millimeters |
|-----|-------------|
| DIN | Тур |
| а | 0.68 |
| В | 1.14 |
| С | 0.58 |
| d | Ф1.55 |
| E | 1.75 |
| F | 3.50 |
| P0 | 4.00 |
| Р | 2.00 |
| P1 | 2.00 |
| W | 8.00 |



User direction of feed

Pin 1 Quadrant: Q1&Q2



| ФА | ΦN | ΦВ | С | W1 | W2 | W3 |
|-------|------|--------|-------|-------|----------------------|-------|
| 178mm | 54mm | 13.2mm | 2.2mm | 9.5mm | 13 _{max} mm | 1.4mm |



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